2N3789 2N3791 2N3790 2N3792

SILICON PNP POWER TRANSISTORS

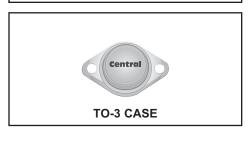


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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N3789, 2N3790, 2N3791, and 2N3792 are silicon PNP power transistors, manufactured by the epitaxial planar process, designed for medium speed switching and amplifier applications.





| MAXIMUM RATINGS: (T _C =25°C) Collector-Base Voltage | SYMBOL V _{CBO} | 2N3789 2N3791 60 | 2N3790 2N3792 80 | UNITS V |
|--|-----------------------------------|--------------------------------------|--------------------------------------|------------|
| Collector-Emitter Voltage | V_{CEO} | 60 | 80 | V |
| Emitter-Base Voltage | V_{EBO} | 7. | 0 | V |
| Continuous Collector Current | IC | 1 | 0 | Α |
| Continuous Base Current | Ι _Β | 4. | 0 | Α |
| Power Dissipation | P_{D} | 15 | 50 | W |
| Operating and Storage Junction Temperature | T _J , T _{stg} | -65 to | +200 | °C |
| Thermal Resistance | ΘJC | 1. | 17 | °C/W |

ELECTRICAL CHARACTERISTICS: (T_C=25°C unless otherwise noted)

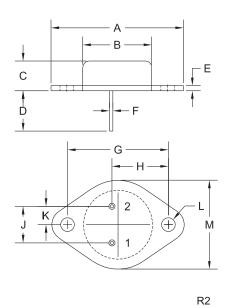
| | | 2N37 2N37 | | | | | |
|-----------------------|---|--------------|-----|-----|-----|-------|--|
| SYMBOL | TEST CONDITIONS | MIN | MAX | MIN | MAX | UNITS | |
| ICEV | V _{CE} =Rated V _{CEO} , V _{EB} =1.5V | - | 1.0 | - | 1.0 | mA | |
| ICEV | V_{CE} =Rated V_{CEO} , V_{EB} =1.5V, T_{C} =150°C | - | 5.0 | - | 5.0 | mA | |
| I _{EBO} | V _{EB} =7.0V | - | 5.0 | - | 5.0 | mA | |
| BVCEO | I _C =200mA | 60 | - | 80 | - | V | |
| V _{CE} (SAT) | I _C =4.0A, I _B =400mA (2N3789, 2N3790) | - | 1.0 | - | 1.0 | V | |
| V _{CE(SAT)} | I _C =5.0A, I _B =500mA (2N3791, 2N3792) | - | 1.0 | - | 1.0 | V | |
| V _{BE(ON)} | V _{CE} =2.0V, I _C =5.0A (2N3789, 2N3790) | - | 2.0 | - | 2.0 | V | |
| V _{BE(ON)} | V _{CE} =2.0V, I _C =5.0A (2N3791, 2N3792) | - | 1.8 | - | 1.8 | V | |
| V _{BE(ON)} | V_{CE} =4.0V, I_{C} =10A | - | 4.0 | - | 4.0 | V | |
| hFE | V _{CE} =2.0V, I _C =1.0A (2N3789, 2N3790) | 25 | 90 | 25 | 90 | | |
| hFE | V _{CE} =2.0V, I _C =1.0A (2N3791, 2N3792) | 50 | 180 | 50 | 180 | | |
| h_{FE} | V _{CE} =2.0V, I _C =3.0A (2N3789, 2N3790) | 15 | - | 15 | - | | |
| hFE | V _{CE} =2.0V, I _C =3.0A (2N3791, 2N3792) | 30 | - | 30 | - | | |
| fT | V _{CE} =10V, I _C =500mA, f=1.0MHz | 4.0 | - | 4.0 | - | MHz | |

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TO-3 CASE - MECHANICAL OUTLINE



| DIMENSIONS | | | | | | | |
|------------|--------|-------|-------------|-------|--|--|--|
| | INCHES | | MILLIMETERS | | | | |
| SYMBOL | MIN | MAX | MIN | MAX | | | |
| Α | 1.516 | 1.573 | 38.50 | 39.96 | | | |
| B (DIA) | 0.748 | 0.875 | 19.00 | 22.23 | | | |
| С | 0.250 | 0.450 | 6.35 | 11.43 | | | |
| D | 0.433 | 0.516 | 11.00 | 13.10 | | | |
| Е | 0.054 | 0.065 | 1.38 | 1.65 | | | |
| F | 0.035 | 0.045 | 0.90 | 1.15 | | | |
| G | 1.177 | 1.197 | 29.90 | 30.40 | | | |
| Н | 0.650 | 0.681 | 16.50 | 17.30 | | | |
| J | 0.420 | 0.440 | 10.67 | 11.18 | | | |
| K | 0.205 | 0.225 | 5.21 | 5.72 | | | |
| L (DIA) | 0.151 | 0.172 | 3.84 | 4.36 | | | |
| М | 0.984 | 1.050 | 25.00 | 26.67 | | | |

TO-3 (REV: R2)

LEAD CODE:

- 1) Base
- 2) Emitter

Case) Collector

MARKING:

FULL PART NUMBER

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



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Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

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Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA

Main Tel: (631) 435-1110 Main Fax: (631) 435-1824

Support Team Fax: (631) 435-3388

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